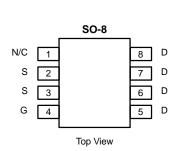
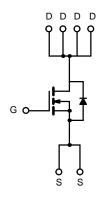


N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(\Omega)$		
	0.030 @ V _{GS} = 10 V	7.0	
30	0.040 @ V _{GS} = 5 V	6.0	
	0.050 @ V _{GS} = 4.5 V	5.4	



Ordering Information: Si9410DY Si9410DY-T1 (with Tape and Reel)



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Limit	Unit			
Drain-Source Voltage		V _{DS}	30	.,		
Gate-Source Voltage		V _{GS}	±20			
Ocationary Desir Compat /T 45000\3	T _A = 25°C		7.0			
Continuous Drain Current (T _J = 150°C) ^a	T _A = 70°C	I _D	5.8			
Pulsed Drain Current		I _{DM}	30	Α		
Continuous Source Current (Diode Conduction) ^a		I _S	2.8			
Manierona Discipations	T _A = 25°C		2.5	14/		
Maximum Power Dissipation ^a	T _A = 70°C	P _D	1.6	W		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Limit	Unit	
Maximum Junction-to-Ambient ^a	R _{thJA}	50	°C/W	

Notes a. Surface Mounted on FR4 Board, $t \le 10$ sec.

 $For \ \ SPICE \ model \ information \ via \ the \ \ Worldwide \ \ Web: \ \ http://www.vishay.com/www/product/spice.htm$

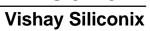
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SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)								
Parameter	Symbol	Test Condition	Min	Typ ^a	Max	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0			V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA		
7 0	I _{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			2			
Zero Gate Voltage Drain Current		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	- μΑ		
On-State Drain Current ^b	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α		
	r _{DS(on)}	V _{GS} = 10 V, I _D =7.0 A		0.024	0.030	Ω		
Drain-Source On-State Resistance ^b		$V_{GS} = 5 \text{ V}, I_D = 4.0 \text{ A}$		0.030	0.040			
		$V_{GS} = 4.5 \text{ V}, I_D = 3.5 \text{ A}$		0.032	0.050			
Forward Transconductance ^b	9fs	$V_{DS} = 15 \text{ V}, I_{D} = 7.0 \text{ A}$		15		S		
Diode Forward Voltage ^b	V _{SD}	$I_S = 2 \text{ A}, V_{GS} = 0 \text{ V}$		0.72	1.1	V		
Dynamic ^a								
Total Gate Charge	Qg			24	50			
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, \ V_{GS} = 10 \text{ V}, \ I_D = 7 \text{ A}$		2.8		nC		
Gate-Drain Charge	Q _{gd}			4.6				
Turn-On Delay Time	t _{d(on)}	V_{DD} = 25 V, R_L = 25 Ω $I_D \cong 1$ A, V_{GEN} = 10 V, R_G = 6 Ω		14	30	ns		
Rise Time	t _r			10	60			
Turn-Off Delay Time	t _{d(off)}			46	150			
Fall Time	t _f			17	140			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2 A, di/dt = 100 A/μs		60				

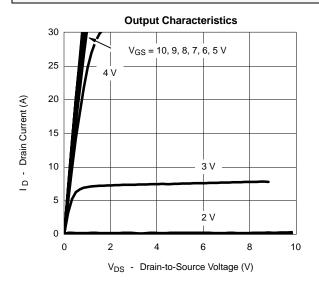
Notes

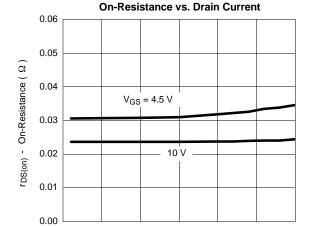
a. Guaranteed by design, not subject to production testing. b. Pulse test; pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$.

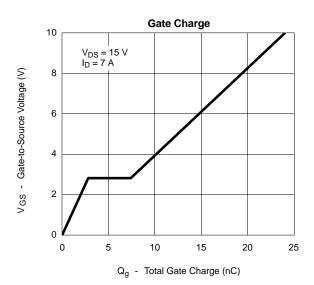


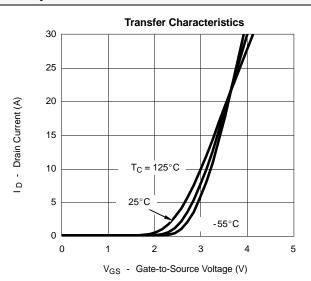


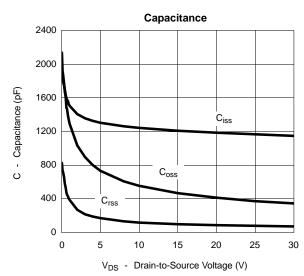
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

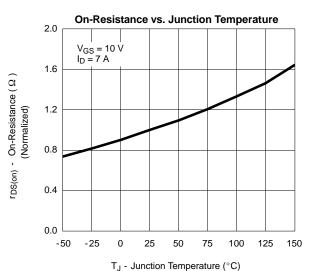












0

5

10

15

I_D - Drain Current (A)

20

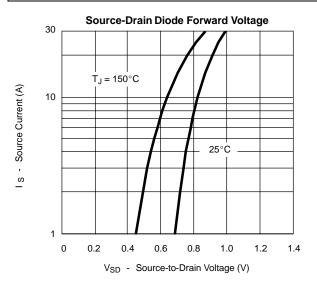
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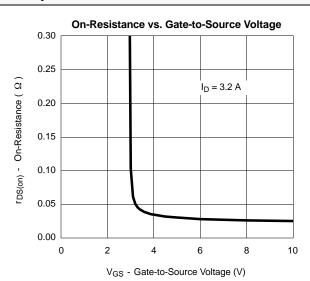
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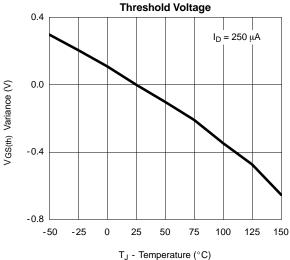
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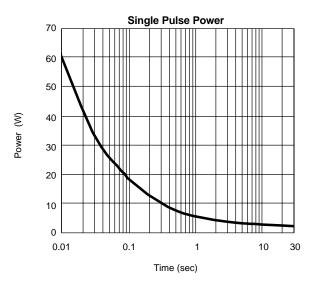


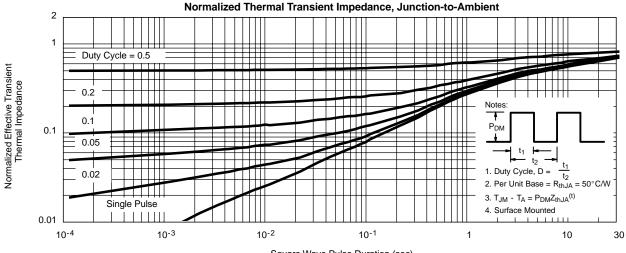
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)













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